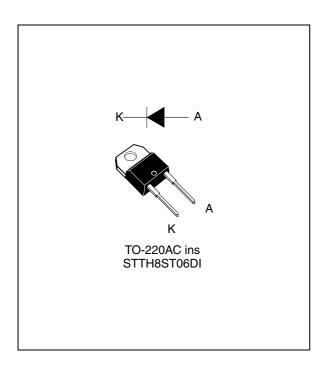
STTH8ST06



600 V tandem extra fast diode

Datasheet - production data



Features

- High voltage rectifier
- · Tandem diodes in series
- · Very low switching losses
- Insulated device with internal ceramic
- Equal thermal conditions for both 300 V diodes
- Static and dynamic equilibrium of internal diodes are warranted by design
- Insulated package:Capacitance: 7 pF
 - Insulated voltage: 2500 V rms

Description

This device is part of ST's second generation of 600 V tandem diodes. It has ultralow switching-losses with a minimized Q_{RR} that makes it perfect for use in circuits working in hard-switching mode. In particular the V_F/Q_{RR} trade-off positions this device between standard ultrafast diodes and silicon-carbide Schottky rectifiers in terms of price/performance ratio.

The device offers a new positioning giving more flexibility to power-circuit designers looking for good performance while still respecting cost constraints.

Featuring ST's Turbo 2 600 V technology, the device is particularly suited as a boost diode in continuous conduction mode power factor correction circuits.

Table 1. Device summary

144010 11 20 1100 0411111141				
Symbol	Value			
I _{F(AV)}	8 A			
V_{RRM}	600 V			
t _{rr} (typ)	13 ns			
I _{RM} (typ)	2 A			
V _F (typ)	2.5 V			
I _{FRM}	40 A			
T _j (max)	175 °C			

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Table 2. Absolute ratings (limiting values at T_j = 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V	Popotitivo poek roverse veltage	T _j from 25 to 150 °C	600	V
V _{RRM}	Repetitive peak reverse voltage	T _j = -40 °C	550	
I _{F(RMS)}	Forward rms current	14	А	
I _{F(AV)}	Average forward current, $\delta = 0.5$	T _c = 80 °C	8	Α
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		55	Α
I _{FRM}	Repetitive peak forward current $T_c = 80 ^{\circ}\text{C}, \delta = 0.1$		40	Α
T _{stg}	Storage temperature range	-65 to +175	°C	
T _j	Operating junction temperature			°C

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2.9	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V- - V			6	μA
'R`	inteverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		20	200	μΛ
V _E (2)	V _E ⁽²⁾ Forward voltage drop		I _ Q A		3.4		V
v _F (=)	Polward voltage drop	T _j = 150 °C	I _F = 8 A		2.5	3.1	V

^{1.} Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 2.2 \text{ x } I_{F(AV)} + 0.113 I_{F(RMS)}^{2}$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

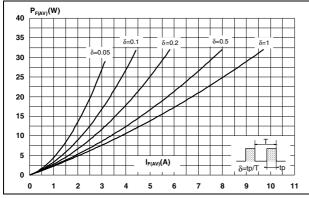
STTH8ST06 Characteristics

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions			Тур.	Max.	Unit
	Reverse recovery time	T = 25 °C	$I_F = 1 \text{ A, V}_R = 30 \text{ V,}$ $dI_F/dt = -50 \text{ A/}\mu\text{s}$		20	26	ns
t _{rr}		T _j = 25 °C	I _F = 8 A, V _R = 400 V, dI _F /dt = -200 A/μs		13	17	
I _{RM}	Reverse recovery current	T _i = 125 °C			2	2.6	Α
S	Softness factor	1 i j = 125 C	$I_F = 8 \text{ A}, V_R = 400 \text{ V},$		0.9		-
0	Powerse recovery charge $T_j = 25^{\circ}$		$dI_F/dt = -200 A/\mu s$		4		nC
Q _{RR}	Reverse recovery charge	T _j = 125 °C			20		

Figure 1. Average forward power dissipation versus average forward current

Figure 2. Forward voltage drop versus forward current (typical values)



100.0 IFM(A)

100.0 IFM(A)

100.0 IFM(A)

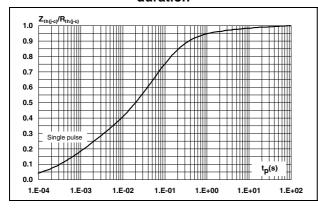
100.0 IFM(A)

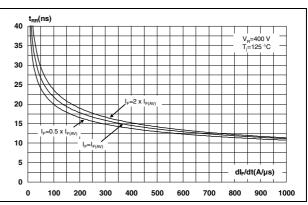
100.0 IFM(B)

10

Figure 3. Relative variation of thermal impedance, junction to case, versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)





Characteristics STTH8ST06

Figure 5. Reverse recovery time versus dl_F/dt (typical values)

15 | I_F=0.5 x | I_F(AV) | I_F=I_F(AV) | I

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)

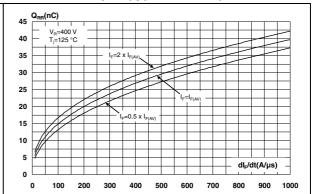


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values)

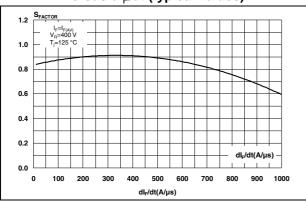


Figure 8. Relative variations of dynamic parameters versus junction temperature

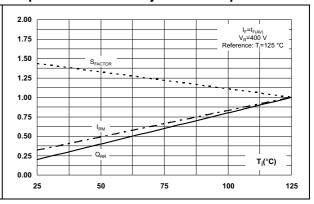
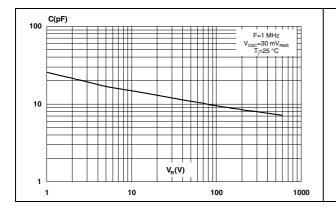
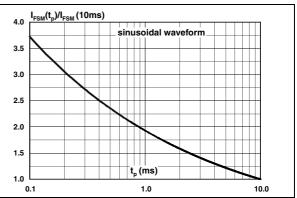


Figure 9. Junction capacitance versus reverse voltage applied (typical values)

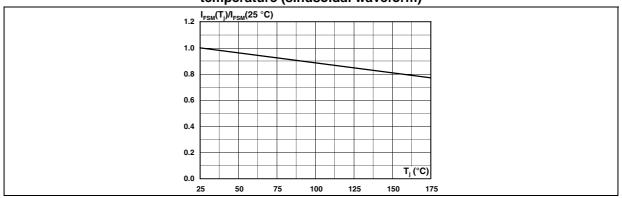
Figure 10. Relative variation of non-repetitive peak surge forward current versus pulse duration





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Figure 11. Relative variation of non-repetitive peak surge forward current versus initial junction temperature (sinusoidal waveform)



Package information STTH8ST06

2 Package information

• Epoxy meets UL94, V0

• Cooling method: by conduction (C)

Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 12. T0-220AC ins dimension definitions

Table 6. T0-220AC ins dimension values

	Dimensions						
Ref.		Millimeters	Millimeters		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	15.20		15.90	0.598		0.625	
a1		3.75			0.147		
a2	13.00		14.00	0.511		0.551	
В	10.00		10.40	0.393		0.409	
b1	0.61		0.88	0.024		0.034	
b2	1.23		1.32	0.048		0.051	
С	4.40		4.60	0.173		0.181	
c1	0.49		0.70	0.019		0.027	
c2	2.40		2.72	0.094		0.107	
е	4.80		5.40	0.189		0.212	
F	6.20		6.60	0.244		0.259	
ØI	3.75		3.85	0.147		0.151	
14	15.80	16.40	16.80	0.622	0.646	0.661	
L	2.65		2.95	0.104		0.116	
12	1.14		1.70	0.044		0.066	
М		2.60			0.102		

Ordering information STTH8ST06

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH8ST06DI	STTH8ST06DI	TO-220AC ins	2.30 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
14-May-2013	1	Initial release

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